PATENT

Docket No.: M4065.123/P123

Micron No.: 98-0611/US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application

Inventors: SANDHU et al.

Serial No.: Not Yet Assigned Group Art Unit:

Not Yet

Assigned

Filed: Concurrently Herewith Examiner: Not Yet Assigned

For: HIGH COUPLING SPLIT-GATE

TRANSISTOR AND METHOD FOR

ITS FORMATION

POWER OF ATTORNEY BY ASSIGNEE AND CERTIFICATE BY ASSIGNEE UNDER 37 CFR § 3.73(b)

Micron Technology, Inc., assignee of the entire right, title and interest in the above-identified application by virtue of the assignment attached hereto (which is also being submitted concurrently for recordation), hereby appoints the attorneys and agents of the firm of Dickstein Shapiro Morin & Oshinsky LLP located at 2101 L Street, NW, Washington, DC 20037-1526, listed as follows: Gary M. Hoffman, 26,411; Thomas J. D'Amico, 28,371; Donald A. Gregory, 28,954; James W. Brady, Jr., 32,115; Jon D. Grossman, 32,699; Mark J. Thronson, 33,082; Laurence D. Fisher, 37,131; John R. Fuisz, 37,327; James M. Heintz, 41,828; June Cohan Lazar, P43,741; Brian A. Lemm, P43,748; Gianni Minutoli, 41,198; Eric Oliver, 35,307; William E. Powell, III, 39,803; James M. Silbermann, 40,413; and Richard Veltman, 36,957; and also attorneys Michael L. Lynch, 30,871; Lia M. Pappas, 34,095; W. Eric Webostad, 35,406; and Charles B. Brantley, II, 38,086 of Micron Technology, Inc. as its attorneys with full power of substitution to prosecute this application and to transact all business in the Patent and Trademark Office in connection therewith.

The assignee certifies that the above-identified assignment has been reviewed and to the best of the assignee's knowledge and belief, title is in the assignee.

Please direct all correspondence regarding this application to the following:

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Michael L. Lynch Chief Patent Counsel Registration No. 30,871

Dated: 4-1-99

Dr '-et No.: M4065.123/P123 \(\lambda \) .ron No.: 98-0611/US

ASSIGNMENT AND AGREEMENT

For value received, we, Gurtej S. Sandhu of Boise, Idaho and Sukesh Sandhu of Boise, Idaho, hereby sell, assign and transfer to Micron Technology Inc., a corporation of the State of Delaware, having an office at 8000 S. Federal Way, Boise, Idaho 83706-9632, U.S.A., and its successors, assigns and legal representatives, the entire right, title and interest, for the United States of America, in and to certain inventions related to an invention entitled HIGH COUPLING SPLIT-GATE TRANSISTOR AND METHOD FOR ITS FORMATION described in an application for Letters Patent of the United States, executed by us of even date herewith, and all the rights and privileges in said application and under any and all Letters Patent that may be granted in the United State for said inventions; and we also concurrently hereby sell, assign and transfer to Micron Technology, Inc. the entire right, title and interest in and to said inventions for all countries foreign to the United States, including all rights of priority arising from the application aforesaid, and all the rights and privileges under any and all forms of protection, including Letters Patent, that may be granted in said countries foreign to the United States for said inventions.

We authorize Micron Technology, Inc. to make application for such protection in its own name and maintain such protection in any and all countries foreign to the United States, and to invoke and claim for any application for patent or other form of protection for said inventions, without further authorization from us, any and all benefits, including the right of priority provided by any and all treaties, conventions, or agreements.

We hereby consent that a copy of this assignment shall be deemed a full legal and formal equivalent of any document which may be required in any country in proof of the right of Micron Technology, Inc. to apply for patent or other form of protection for said inventions and to claim the aforesaid benefit of the right of priority.

We request that any and all patents for said inventions be issued to Micron Technology, Inc. in the United States and in all countries foreign to the United States, or to such nominees as Micron Technology, Inc. may designate.

We agree that, when requested, we shall, without charge to Micron Technology, Inc. but at its expense, sign all papers, and do all acts which may be necessary, desirable or convenient in connection with said applications, patents, or other forms of protection.

Dc 1-et No.: M4065.123/P123 cron No.: 98-0611/US

Gurtej S. Sandhu

Date: 4/1/29

United States of America)
State of _______)ss.:
County of ______)

On this \(\sum \) day of \(\text{QMM} \), 1999, before me personally came Gurtej S. Sandhu, to me known to be the individual described in and who executed the foregoing instrument, and acknowledged execution of the same.

Notary Public

Dr 'e' No.: M4065.123/P123 \(\) ron No.: 98-0611/US

	Sukesh Sandhu Sukesh Sandhu
Date: 4/1/99	
United States of America) State of <u>Odaho</u>)ss.: County of <u>Odaho</u>)	
On this day of	1999, before me personally came Sukesh idual described in and who executed the foregoing ion of the same.
	Notary Public